NSN 5961-00-520-3453

Transistor - Page 1 of 1



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Inclosure Material:

Metal

End Application:

Aircraft, galaxy c-5

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

Mounting Method:

Terminal

Criticality Code Justification:

Feat

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

190.0 collector to base voltage/static/emitter open and 180.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open

Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector absolute

Special Features:

Junction pattern arrangement: npn; weapon system essential

Test Data Document:

97896-341-0287 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) and 97896-341-0276 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

2 pin and 1 case

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0